

Supporting information

Ideal Strength and Strain Engineering of Rashba Effect in Two-Dimensional BiTeBr

Wei Yang,^a Zhizi Guan,^a Hailong Wang,^{a,*} and Junwen Li^{b,*}

^aCAS Key Laboratory of Mechanical Behavior and Design of Materials, Department of Modern Mechanics, CAS Center for Excellence in Complex System Mechanics, University of Science and Technology of China, Hefei, Anhui 230027, China

^bDFTWorks LLC, Oakton, VA 22124, USA

To verify the stability calculation based on our stress-strain curve, we also carry out the calculations of elastic stiffness constants of BiTeBr monolayers. With the Born-Huang stability criteria as described by

$$C_{11} > 0, C_{22} > 0, C_{11} > |C_{12}|, C_{66} > 0,$$

we find these structures remain stable under the critical strain of 15% as listed in Tab. S1. This is in good agreement with the stress-strain curve in Fig. 2.

Tab. S1. Elastic Stiffness Constants of BiTeBr monolayer under the biaxial strain from 0 to 17%.

Strain(%)	C ₁₁ (N/m)	C ₁₂ (N/m)	C ₂₂ (N/m)	C ₆₆ (N/m)
0	28.612	7.224	28.612	10.694
7	20.727	3.920	20.727	8.403
10	17.569	2.036	17.569	7.767
13	13.545	0.335	13.545	6.605
15	25.418	6.598	25.418	9.410
16	-6.261	12.698	-6.261	-9.480
17	-29.849	32.959	-29.849	-31.404

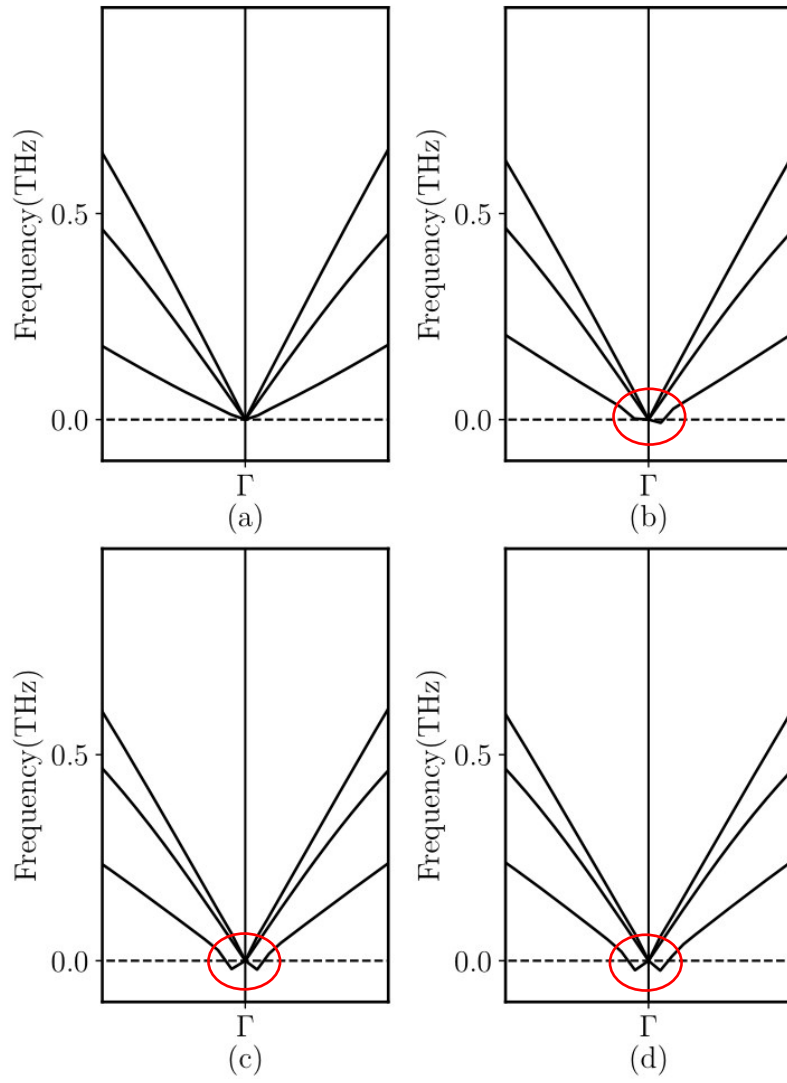


Fig. S1. The small virtual frequencies around Γ point in phonon spectra under a biaxial tensile strain (a) $\epsilon = 0\%$, (b) $\epsilon = 3\%$, (c) $\epsilon = 7\%$ and (d) $\epsilon = 8\%$.

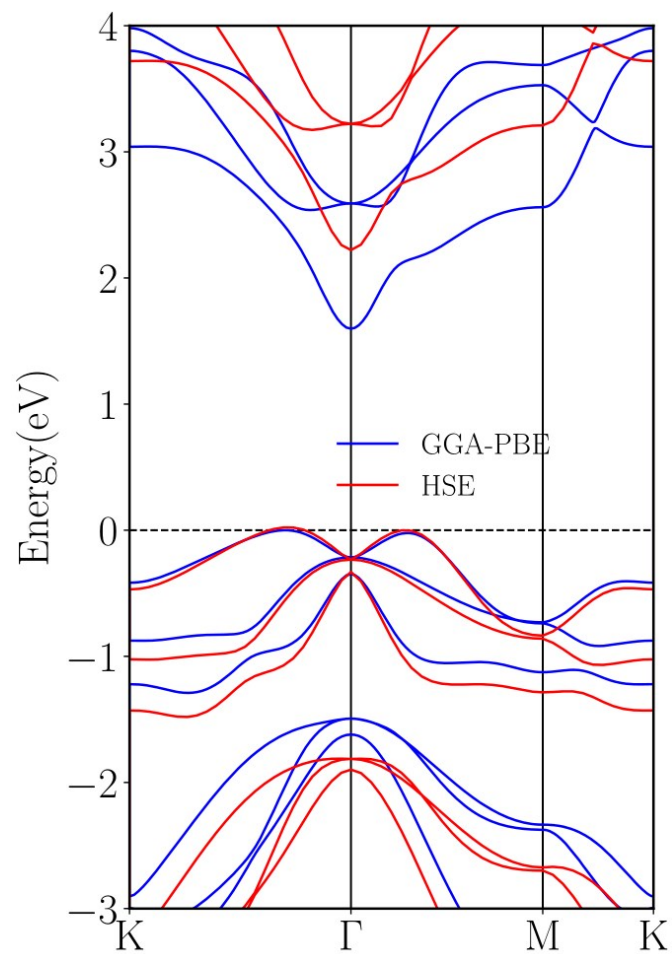


Fig. S2. Electronic band structures calculated using PBE (blue) and HSE06 (red) for a strain-free monolayer without considering spin-orbit coupling.

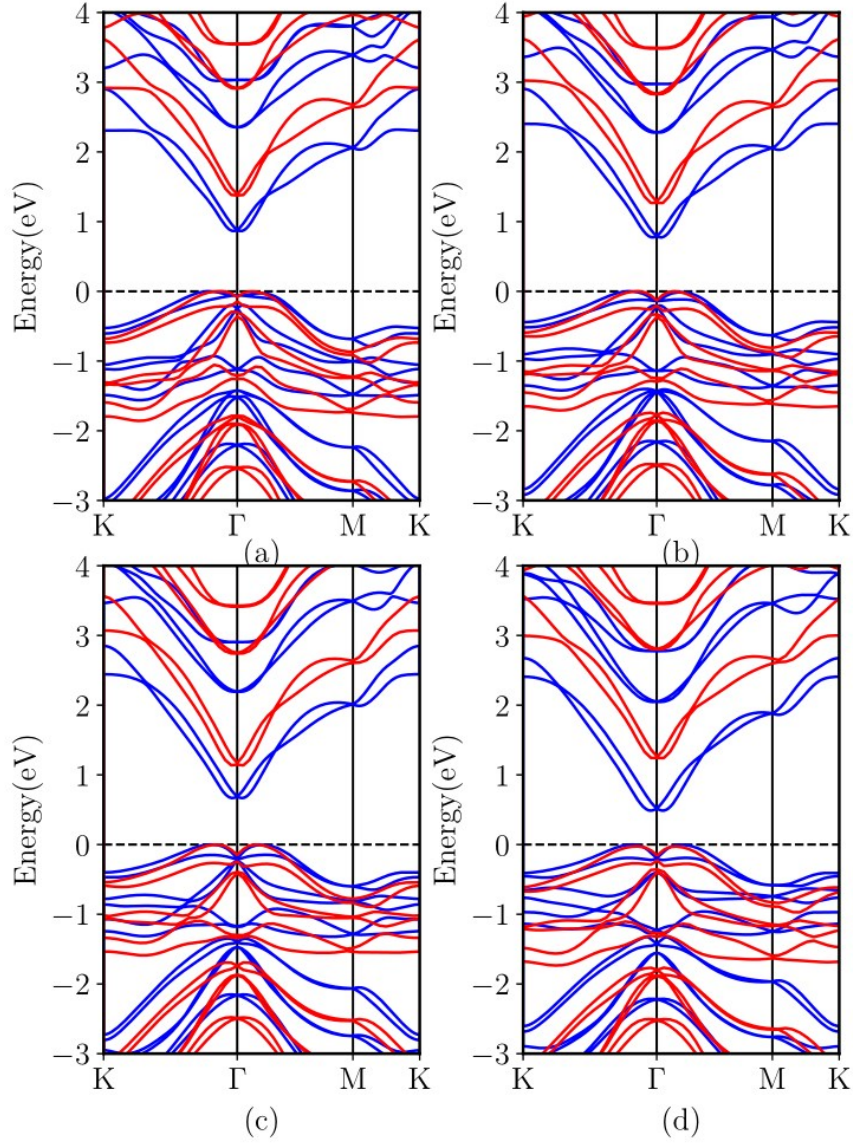


Fig. S3. Electronic band structures of BiTeBr monolayer using PBE (blue) and HSE06 (red) under the applied strain of (a) 0%, (b) 2%, (c) 4% and (d) 7% with spin-orbit coupling included.

Although the BiTeBr monolayer is mechanically stable and dynamically stable when the biaxial tensile strain less than 8%. Here we also present the dependencies of the characteristic parameters of the Rashba spin splitting on the strains in range of 0 to 15% as supplements.

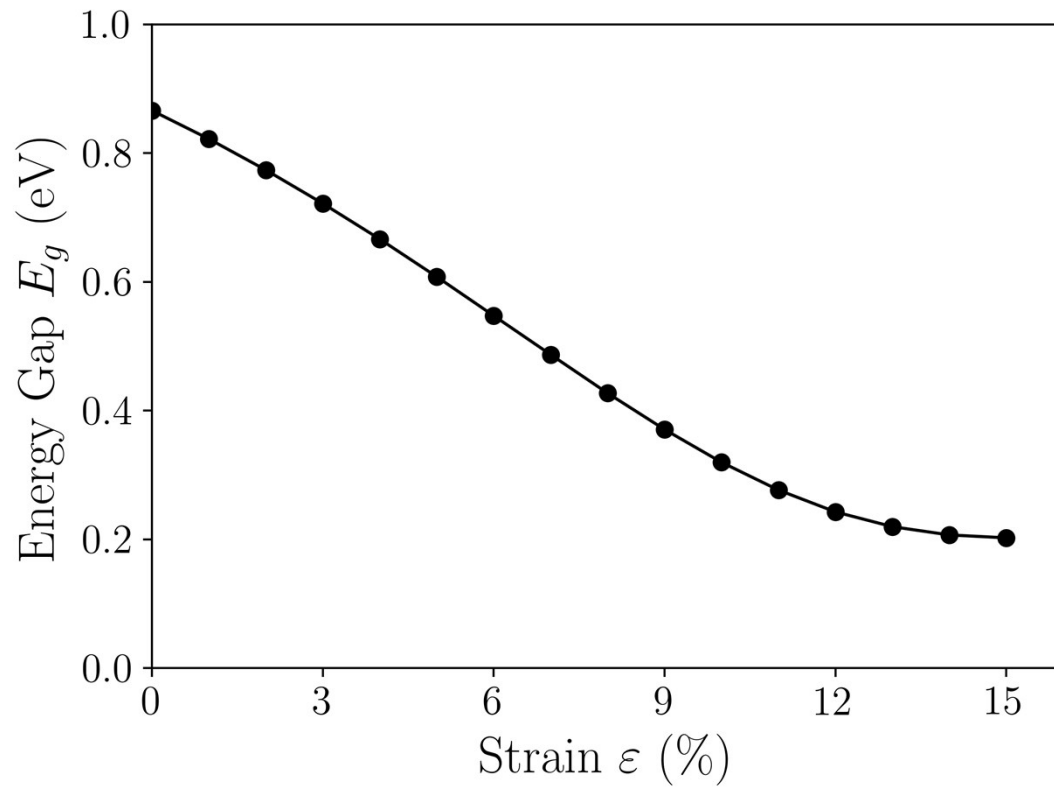


Fig. S4. The PBE energy gap E_g as a function of strain. The band structure demonstrates indirect band gap within the range of all strains.

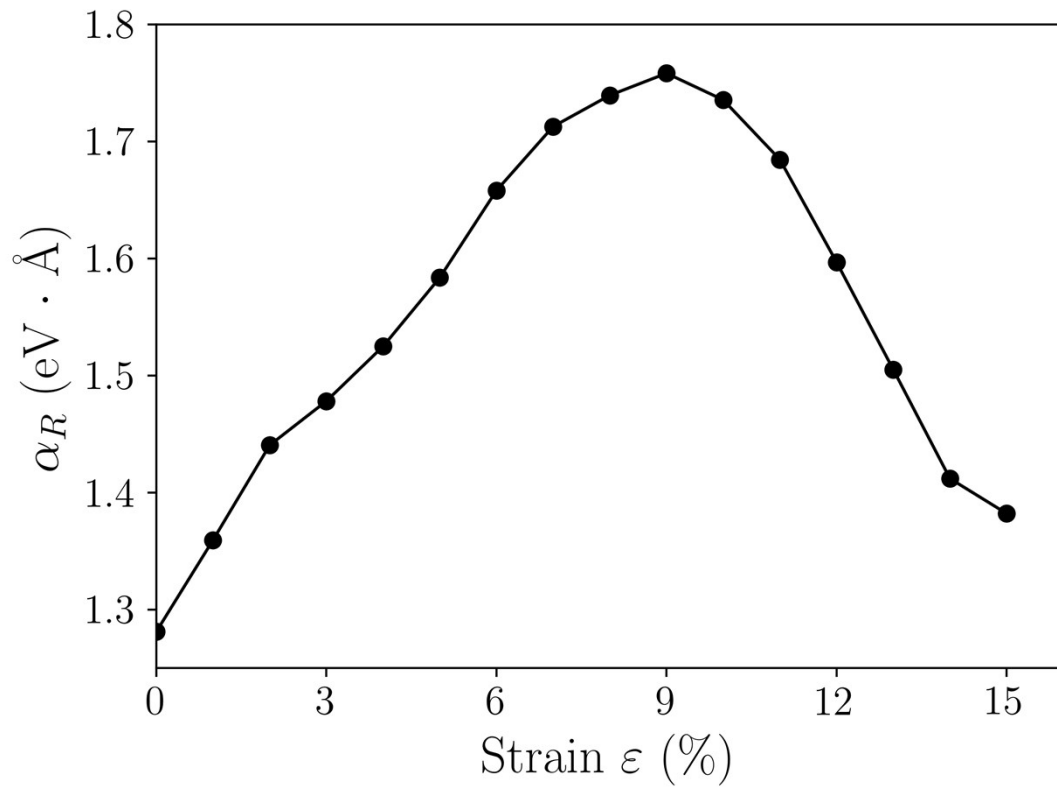


Fig. S5. The PBE Rashba parameter α_R as a function of strain, calculated for the conduction band minimum around the Γ point.

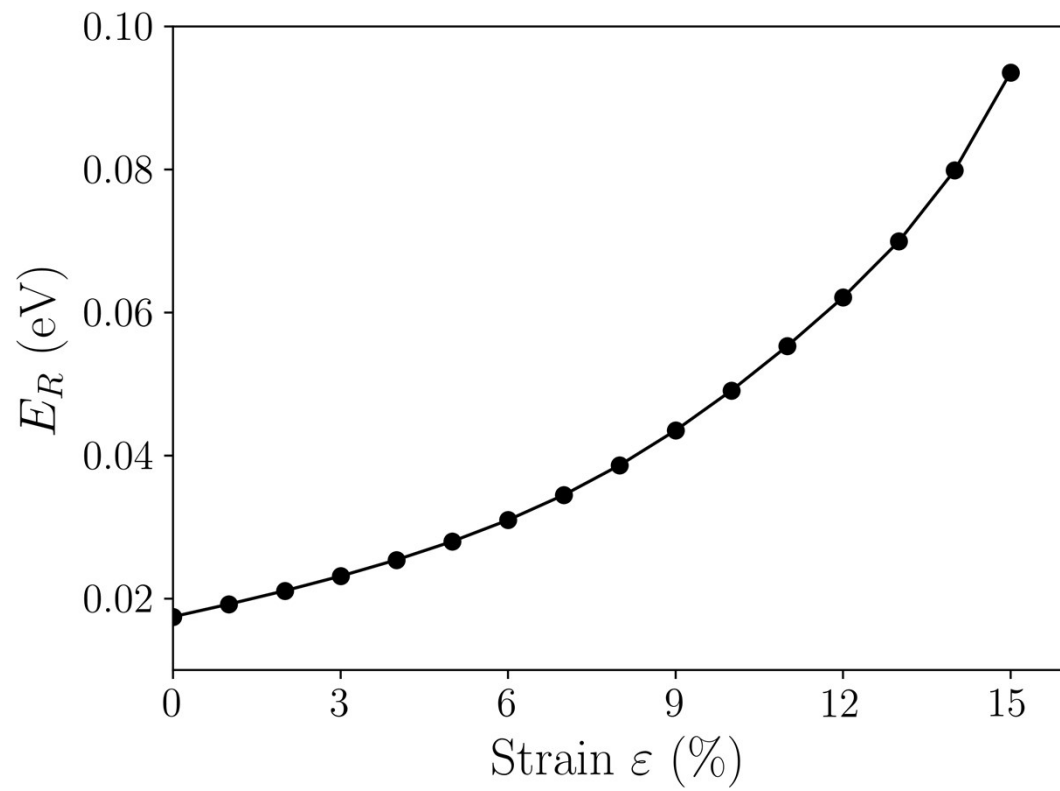


Fig. S6. The PBE Rashba Energy E_R as a function of strain, calculated for the conduction band minimum around the Γ point.

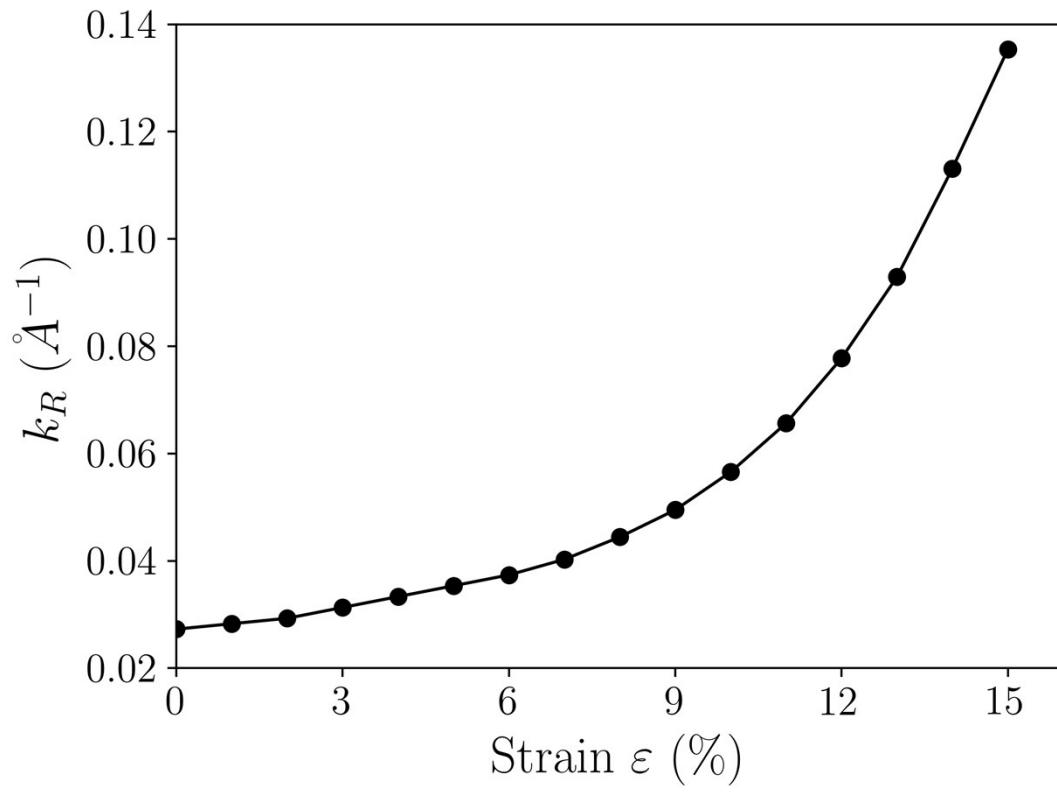


Fig. S7. The PBE momentum offset k_R as a function of strain, calculated for the conduction band minimum around the Γ point.